

# 16 A Three-quadrant triacs high commutation Rev. 01 — 11 April 2007

**Product data sheet** 

### **Product profile**

### 1.1 General description

Passivated, new generation, high commutation triacs in a SOT78 plastic package

### 1.2 Features

- Very high commutation performance maximized at each gate sensitivity
- High immunity to dV/dt

### 1.3 Applications

- High power motor control e.g. washing
   Refrigeration and air conditioning machines and vacuum cleaners
- Non-linear rectifier-fed motor loads
- compressors
- Electronic thermostats

#### 1.4 Quick reference data

- $V_{DRM} \le 600 \text{ V (BTA316-600B/C)}$
- $V_{DRM} \le 800 \text{ V (BTA316-800B/C)}$
- $I_{TSM} \le 140 \text{ A (t = 20 ms)}$
- I<sub>GT</sub>  $\leq$  50 mA (BTA316 series B)
- I<sub>GT</sub>  $\leq$  35 mA (BTA316 series C)
- $I_{T(RMS)} \le 16 A$

# **Pinning information**

Table 1. **Pinning** 

Pin	Description	Simplified outline	Symbol
1	main terminal 1 (T1)		<b>.</b> .
2	main terminal 2 (T2)	mb	T2—T1
3	gate (G)		sym051
mb	mounting base; main terminal 2 (T2)	1 2 3	
		SOT78 (TO-220AB)	



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# 3. Ordering information

#### Table 2. Ordering information

Type number	Package				
	Name	Description	Version		
BTA316-600B	SC-46	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead	SOT78		
BTA316-600C		TO-220AB			
BTA316-800B					
BTA316-800C					

# 4. Limiting values

#### Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DRM}$	repetitive peak off-state voltage	BTA316-600B; BTA316-600C	<u>[1]</u> _	600	V
		BTA316-800B; BTA316-800C	-	800	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; $T_{mb} \le 101$ °C; see Figure 4 and 5	-	16	Α
I <sub>TSM</sub>	non-repetitive peak on-state current	full sine wave; $T_j = 25$ °C prior to surge; see Figure 2 and 3			
		t = 20 ms	-	140	Α
		t = 16.7 ms	-	150	Α
I <sup>2</sup> t	I <sup>2</sup> t for fusing	t = 10 ms	-	98	A <sup>2</sup> s
dl <sub>T</sub> /dt	rate of rise of on-state current	$I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu\text{s}$	-	100	A/μs
$I_{GM}$	peak gate current		-	2	Α
$P_{GM}$	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	W
T <sub>stg</sub>	storage temperature		-40	+150	°C
Tj	junction temperature		-	125	°C

<sup>[1]</sup> Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/µs.

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 $\alpha$  = conduction angle

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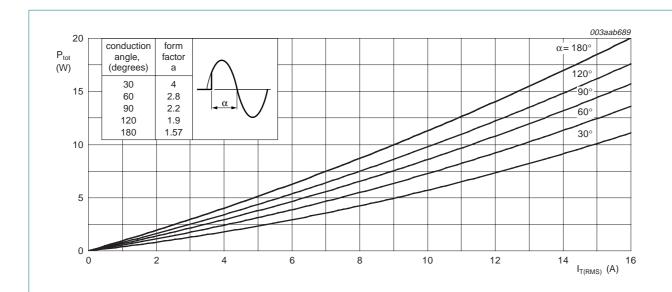


Fig 1. Total power dissipation as a function of RMS on-state current; maximum values

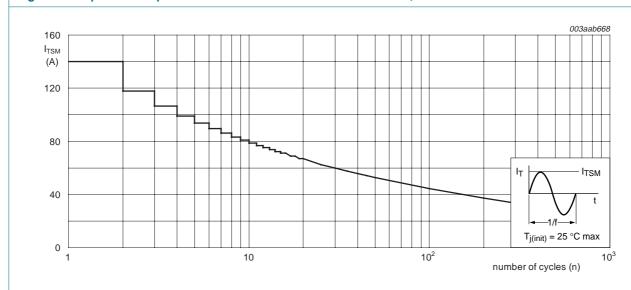
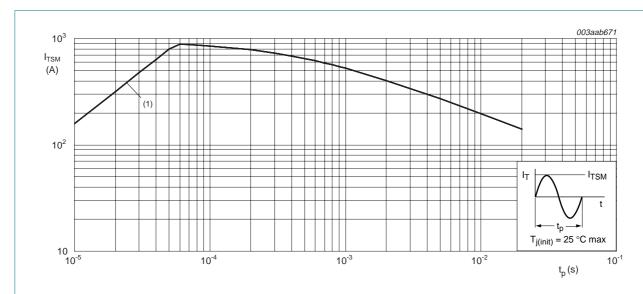


Fig 2. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

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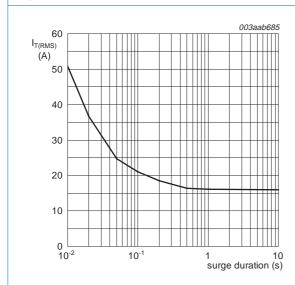
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 $t_p \le 20 \text{ ms}$ 

(1) dl<sub>T</sub>/dt limit

Fig 3. Non-repetitive peak on-state current as a function of pulse duration; maximum values



f = 50 Hz;

T<sub>mb</sub> = 101 °C

Fig 4. RMS on-state current as a function of surge duration; maximum values

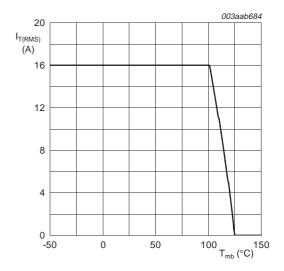


Fig 5. RMS on-state current as a function of mounting base temperature; maximum values

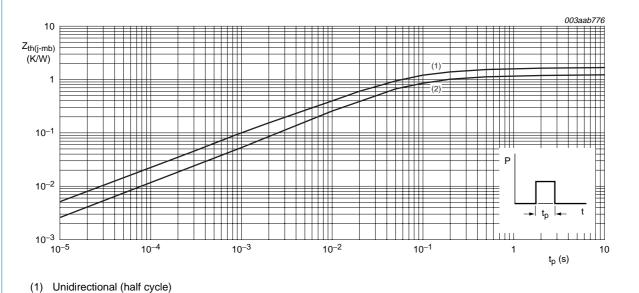
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### Thermal characteristics

Table 4. **Thermal characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	half cycle; see Figure 6	-	-	1.7	K/W
		full cycle; see Figure 6	-	-	1.2	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	-	60	-	K/W



- (2) Bidirectional (full cycle)

Fig 6. Transient thermal impedance from junction to mounting base as a function of pulse duration

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# **Static characteristics**

**Static characteristics** Table 5.

 $T_i = 25 \,^{\circ}C$  unless otherwise specified.

Parameter	Conditions		BTA316-600B BTA316-800B			BTA316-600C BTA316-800C		
		Min	Тур	Max	Min	Тур	Max	
gate trigger	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ see } \frac{\text{Figure 8}}{}$		'	'	'	'		
current	T2+ G+	2	-	50	2	-	35	mA
	T2+ G-	2	-	50	2	-	35	mA
	T2- G-	2	-	50	2	-	35	mA
latching current	$V_D = 12 \text{ V}; I_{GT} = 0.1 \text{ A}; \text{ see } \frac{\text{Figure 10}}{\text{Figure 10}}$							
	T2+ G+	-	-	60	-	-	50	mA
	T2+ G-	-	-	90	-	-	60	mA
	T2- G-	-	-	60	-	-	50	mA
holding current	$V_D = 12 \text{ V}; I_{GT} = 0.1 \text{ A}; \text{ see } \frac{\text{Figure } 11}{\text{Figure } 11}$	-	-	60	-	-	35	mA
on-state voltage	I <sub>T</sub> = 18 A; see <u>Figure 9</u>	-	1.3	1.5	-	1.3	1.5	V
gate trigger	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ see } \frac{\text{Figure 7}}{}$	-	8.0	1.5	-	8.0	1.5	V
voltage	$V_D = 400 \text{ V}; I_T = 0.1 \text{ A}; T_j = 125 ^{\circ}\text{C}$	0.25	0.4	-	0.25	0.4	-	V
off-state current	$V_D = V_{DRM(max)}$ ; $T_j = 125  ^{\circ}C$	-	0.1	0.5	-	0.1	0.5	mΑ
	gate trigger current  latching current  holding current on-state voltage gate trigger voltage			$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{ c c c c c c } \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} \\ \hline \text{gate trigger} & V_D = 12 \ V; \ I_T = 0.1 \ A; \ see \ Figure \ 8 \\ \hline T2+ \ G+ & 2 & - & 50 & 2 \\ \hline T2+ \ G- & 2 & - & 50 & 2 \\ \hline T2- \ G- & 2 & - & 50 & 2 \\ \hline \text{Itching current} & V_D = 12 \ V; \ I_{GT} = 0.1 \ A; \ see \ Figure \ 10 \\ \hline T2+ \ G- & - & 60 & - \\ \hline T2+ \ G- & - & 60 & - \\ \hline T2- \ G- & - & 60 & - \\ \hline \text{Nolding current} & V_D = 12 \ V; \ I_{GT} = 0.1 \ A; \ see \ Figure \ 11 & - & - & 60 & - \\ \hline \text{Nolding current} & V_D = 12 \ V; \ I_{GT} = 0.1 \ A; \ see \ Figure \ 11 & - & - & 60 & - \\ \hline \text{Nolding current} & V_D = 12 \ V; \ I_{GT} = 0.1 \ A; \ see \ Figure \ 11 & - & - & 60 & - \\ \hline \text{Nolding current} & V_D = 12 \ V; \ I_{T} = 0.1 \ A; \ see \ Figure \ 7 & - & 0.8 & 1.5 & - \\ \hline \text{Voltage} & V_D = 400 \ V; \ I_T = 0.1 \ A; \ T_j = 125 \ ^{\circ}C & 0.25 \ 0.4 & - & 0.25 \\ \hline \end{array}$	$ \begin{array}{ c c c c c c } \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Min} & \text{Min} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Min} & \text{Min} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Min} & \text{Min} & \text{Min} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Min} & \text{Min} & \text{Min} & \text{Min} & \text{Min} \\ \hline \text{Min} & \text{Min} $	$ \begin{array}{ c c c c c } \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} & \text{Max} \\ \hline \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} & \text{Max} \\ \hline \text{Min} & \text{Min} & \text{Typ} & \text{Max} & \text{Min} & \text{Typ} & \text{Max} \\ \hline \text{Min} & \text{Min} & \text{Min} & Min$

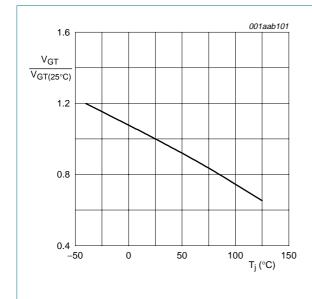
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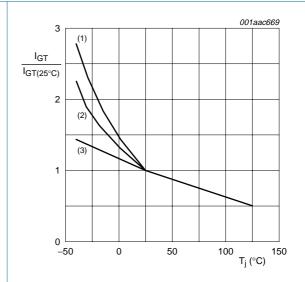
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# 7. Dynamic characteristics

Table 6. Dynamic characteristics

Symbol	Parameter	Conditions	BTA316-600B BTA316-800B			BTA316-600C BTA316-800C			Unit
			Min	Тур	Max	Min	Тур	Max	
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM} = 0.67 \times V_{DRM(max)}; T_j = 125 ^{\circ}C;$ exponential waveform; gate open circuit	1000	-	-	500	-	-	V/μs
dI <sub>com</sub> /dt	rate of change of commutating current	$V_{DM} = 400 \text{ V}; T_j = 125 ^{\circ}\text{C}; I_{T(RMS)} = 16 \text{ A};$ without snubber; gate open circuit	20	-	-	15	-	-	A/ms
t <sub>gt</sub>	gate-controlled turn-on time	$I_{TM} = 20 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A}/\mu\text{s}$	-	2	-	-	2	-	μs



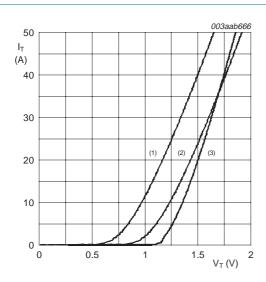


- (1) T2-G-
- (2) T2+ G-
- (3) T2+ G+

Fig 7. Normalized gate trigger voltage as a function of junction temperature

Fig 8. Normalized gate trigger current as a function of junction temperature

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 $V_0 = 1.024 \text{ V}$ 

 $R_s = 0.021 \Omega$ 

- (1)  $T_i = 125$  °C; typical values
- (2)  $T_j = 125 \,^{\circ}C$ ; maximum values
- (3)  $T_j = 25$  °C; maximum values

Fig 9. On-state current as a function of on-state voltage

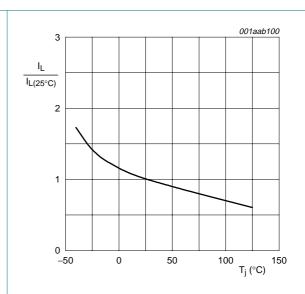


Fig 10. Normalized latching current as a function of junction temperature

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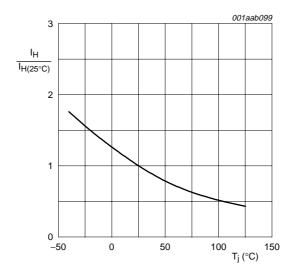


Fig 11. Normalized holding current as a function of junction temperature

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# 8. Package outline

Plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB SOT78

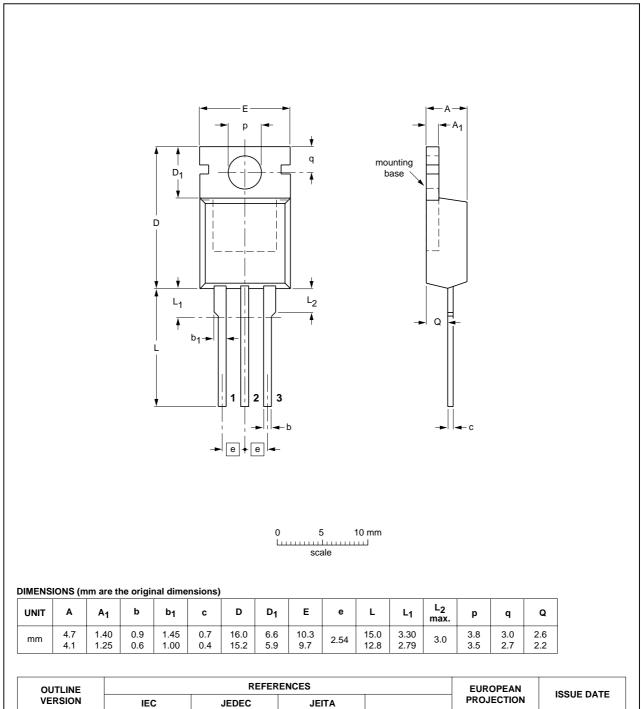


Fig 12. Package outline SOT78 (3-lead TO-220AB)

SOT78

SC-46

3-lead TO-220AB

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# **Revision history**

#### Table 7. **Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
BTA316_SER_B_C_1	20070411	Product data sheet	-	-

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### 10. Legal information

#### 10.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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